

STPS20SM120S

Power Schottky rectifier

Datasheet - production data

I²PAK

STPS20SM120SR

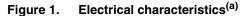
Features

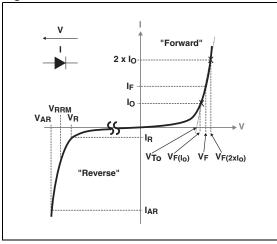
- High current capability
- Avalanche rated
- Low forward voltage drop
- High frequency operation

Description

This Schottky diode is suited for high frequency switch mode power supply.

Packaged in TO-220AB narrow leads and I²PAK, this device is intended to be used in notebook, game station and desktop adapters, providing in these applications a good efficiency at both low and high load.





Doc ID 022921 Rev 1



This is information on a product in full production.

 Table 1.
 Device summary

TO-220AB narrow leads

STPS20SM120STN

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Symbol	Value
I _{F(AV)}	20 A
V _{RRM}	120 V
V _F (typ)	0.49 V
T _j (max)	150 °C

a. V_{ARM} and I_{ARM} must respect the reverse safe operating area defined in *Figure 9*. V_{AR} and I_{AR} are pulse measurements ($t_p < 10 \ \mu$ s). V_R, I_R, V_{RRM} and V_F, are static characteristics

1 **Characteristics**

Absolute ratings (limiting values with terminals 1 and 3 short circuited at Table 2. T_{amb} = 25 °C, unless otherwise specified)

Symbo I		Value	Unit		
V _{RRM}	Repetitive peak reverse v	voltage		120	V
I _{F(RMS)}	Forward rms current			50	А
I _{F(AV)}	Average forward current,	δ = 0.5	T _c = 120 °C	20	А
I _{FSM}	Surge non repetitive forw	ard current	t_p = 10 ms sinusoidal, T_c = 25 °C	220	А
P _{ARM} ⁽¹⁾	Repetitive peak avalanch	e power	T _j = 125 °C, t _p = 10 μs	900	W
V _{ARM} ⁽²⁾	Maximum repetitive peak avalanche voltage	t _p < 10 μs, T _j < 125 °C, I _{AR} < 6A			V
V _{ASM} ⁽²⁾	Maximum single-pulse peak avalanche voltage	t _p < 10 μs, T _j < 125 °C, I _{AR} < 6A			V
T _{stg}	Storage temperature rang	ge			°C
Тj	Maximum operating junction temperature ⁽³⁾				°C

For pulse time duration deratings, please refer to *Figure 4*. More details regarding the avalanche energy measurements and diode validation in the avalanche are provided in the STMicroelectronics Application notes AN1768, "Admissible avalanche power of schottky diodes" and AN2025, "Converter improvement using Schottky rectifier avalanche specification".

2. See Figure 9

 $\frac{dPtot}{dTj} < \frac{1}{Rth(j-a)}$ condition to avoid thermal runaway for a diode on its own heatsink З.

Table 3. Thermal resistance

Symbol	Parameter	Value	Unit
R _{th(j-c)}	Junction to case	1.55	°C/W

Table 4.	Static electrical	characteristics	terminals 1	and 3 short circuited)

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I _B ⁽¹⁾	Reverse leakage current	T _j = 25 °C	V _V	-	40	210	μA
'R`′		T _j = 125 °C	V _R =V _{RRM}	-	15	40	mA
VF ⁽²⁾	Forward voltage drop	T _j = 125 °C	I _F = 5 A	-	0.49	0.54	
		T _j = 25 °C	I _F = 10 A	-		0.75	
		T _j = 125 °C		-	0.57	0.62	V
		T _j = 25 °C	I _F = 20 A	-		0.89	
		T _j = 125 °C		-	0.65	0.72	

1. Pulse test: $t_p = 5 \text{ ms}, \delta < 2\%$

2. Pulse test: $t_p = 380 \ \mu s, \ \delta < 2\%$

To evaluate the conduction losses use the following equation: P = 0.56 x ${I_{F(AV)}}$ + 0.008 x ${I_{F(RMS)}}^2$



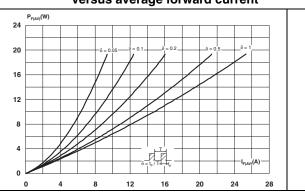
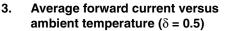


Figure 2. Average forward power dissipation Figure 3. versus average forward current



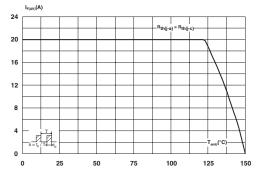


Figure 4. Normalized avalanche power derating versus pulse duration

Figure 5. Relative variation of thermal impedance junction to case versus pulse duration

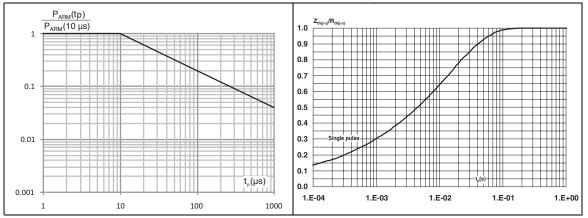
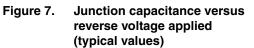
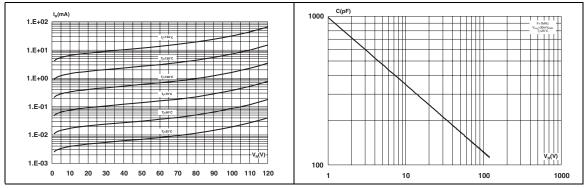


Figure 6. Reverse leakage current versus reverse voltage applied (typical values)





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I_{FM}(A) 1000.0

=

100.0

10.0

1.0

0.1

0.0 0.2 0.4 0.6 0.8 1.0 1.2 1.4 1.6

Figure 8. Forward voltage drop versus forward current

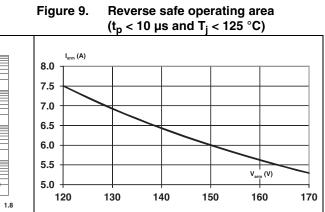


Figure 9.

FM(V)-

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2 Package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.4 to 0.6 N·m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: <u>www.st.com</u>. ECOPACK[®] is an ST trademark.

Table 5. TO-220AB narrow leads dimensions

				Dimer	sions		
	Ref.	М	illimete	rs		Inches	
		Min.	Тур.	Max.	Min.	Тур.	Max.
	А	4.40		4.60	0.17		0.18
	b	0.61		0.88	0.024		0.034
øp A	b1	0.95		1.20	0.037		0.047
	С	0.48		0.70	0.019		0.027
	D	15.25		15.75	0.60		0.62
	D1		1.27			0.05	
	Е	10.00		10.40	0.39		0.41
	е	2.40		2.70	0.094		0.106
	e1	4.95		5.15	0.19		0.20
	F	1.23		1.32	0.048		0.052
	H1	6.20		6.60	0.24		0.26
	J1	2.40		2.72	0.095		0.107
-e1	L	13.00		14.00	0.51		0.55
	L1	2.60		2.90	0.102		0.114
	L20		15.40			0.61	
	L30		28.90			1.14	
	ØP	3.75		3.85	0.147		0.151
	Q	2.65		2.95	0.104		0.116

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Devices in I²PAK with nickel-plated back frame must NOT be mounted by frame soldering like SMDs. Such devices are intended to be through-hole mounted ONLY and in no circumstances shall ST be held liable for any lack of performance or damage arising out of soldering of nickel-plated back frames.

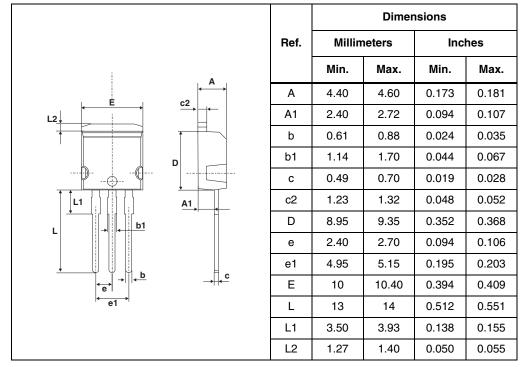


Table 6.I²PAK dimensions



3 Ordering information

Table 7. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS20SM120SR	PS20SM120SR	I ² PAK	1.49 g	50	Tube
STPS20SM120STN	PS20SM120STN	TO-220AB narrow leads	1.9 g	50	Tube

4 Revision history

Table 8.Document revision history

Date	Revision	Changes
02-Apr-2012	1	First issue.



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